



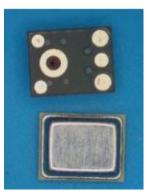
# PRSensors & Systems, Inc. Acoustic Sensors for mobile communication world

# **Analog Bottom Mount MEMS Microphone**

# IRS-3526-AB-3870

Integrating IR Sensors' advanced silicon microphones into your products significantly elevates the user experience. These microphones offer exceptional sound quality, characterized by a high signal-to-noise ratio (SNR), enhanced output sensitivity, and a low cut-off frequency. Additionally, users enjoy prolonged battery life thanks to the microphones' low power consumption, while their dustproof and waterproof design ensures increased reliability.

As a product manufacturer, you will value the microphones' compact form factor and seamless single-output integration, which allows for easy replacement of existing options. They are available in both tape & reel or tube packaging to suit your needs. With a network of global foundry partners, we minimize delivery risks and supply chain disruptions. Experience the next generation of MEMS microphones, engineered to enhance the quality and reliability of your products.



### **Description**

The IR-3526-AB-3870 series of MEMS capacitive silicon microphones feature a patented, next-generation design tailored to meet the diverse needs of customer applications and evolving market demands. Utilizing advanced capacitive sensing technology, this platform offers an extensive signal-to-noise ratio (SNR) range from -60dB to -80dB and beyond, positioning it to comply with future microphone standards.

Our unique, patented designs and processes produce world-class microphones specifically engineered for high-volume, high-performance applications. This innovation enables an exceptional signal-to-noise ratio (SNR) in a smaller die size, allowing for compact packaging that meets the growing demand for smaller footprints in future applications.

### **Features**

- High SNR > 67dB
- Low Noise
- Omni directional
- Small SMD package
- High sensitivity, -38dB typical
- JEDEC compatible
- Bottom & top mount
- RoHS compatible
- Low frequency roll off by design, 20 Hz, typical
- Intrinsically waterproof and dustproof
- Tape & Reel packaging or tube packaging
- Low current consumption, < 130 uA

#### **Typical Applications**

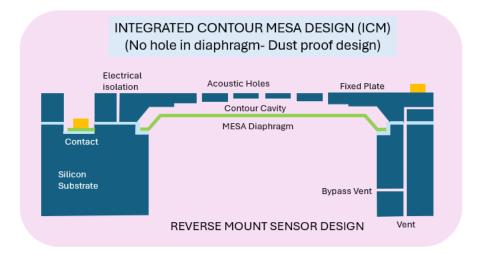
- Mobile Phones
- · Audio devices
- Earphone and Earbud
- Laptop / PC / Tablet
- Automotive
- Remote Sensing
- Door Bell
- Home Automation
- Camera



### The Crown Jewel of MEMS microphones

The IR microphone sensor introduces groundbreaking technology that enables a reduction of up to 60% in package volume and power consumption compared to competitors, all while maintaining the same high signal-to-noise ratio (SNR). This innovation not only addresses the increasing demand for miniaturization but also enhances energy efficiency, making it the perfect solution for compact, power-sensitive applications.

IR's innovative two substrates design and fabrication



Our unique, patented technology integrates several innovative features, including a trapezoidal diaphragm design and contoured cavity, which work together to enhance sensitivity and minimize acoustic noise. This design allows the IR microphone sensor to achieve an SNR of -80dB with a single output and a compact footprint, making it perfect for high-performance applications where space is limited.

### **Order Information**

Product ID	Package	Marking/Order Code
IR3526AB3870	MP-B-3526-70	IR03

Acoustic Sensors for mobile communication world





# PRODUCT KEY PERFORMANCE SPECIFICATIONS

**Product Specification** 

Technical Specification: All data taken at 25±2°C, Relative Humidity 45±5% unless otherwise specified. General Ratings Specifications

SPECIFICATION	MINIMUM	TYPICAL	MAXIMUM	UNITS
Operating Temperature	-40	-	+85	°C
Storage Temperature	-40	-	+100	°C
MSL (moisture sensitivity Level)	Class 1			

### **Product Key Acoustic Performance Specification**

PARAMETER	SYMBOL	TEST CONDITION		VALUE	ES	UNITS
			MIN	TYP	MAX	
Directivity			Om	ni-direc	tional	
Sensitivity	S	94 dB SPL @ 1kHz	-40	-38	-36	dB V/Pa
Signal to Noise Ratio	SNR	94 dB SPL @ 1kHz, A-weighted		70		dB
Total Harmonic Distortion	THD	94 dB SPL @ 1kHz			0.1	%
Acoustic Over Pressure	AOP	10% THD @ 1kHz		>130		dB SPL
Low Frequency Cut-off	LFCO			20		Hz
High Frequency Flatness		+3dB relative to @ 1KHz		10		kHz



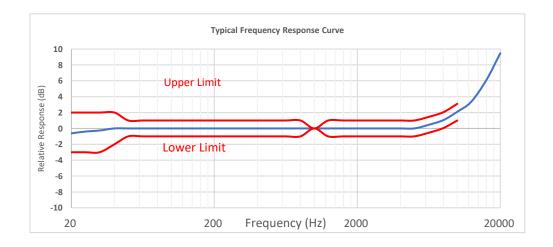
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# **Electrical Key Characteristics and Performance**

			1			
PARAMETER	SYMBOL	TEST CONDITION		VALUES		UNITS
			MIN	TYP	MAX	
Input / Supply Voltage	Vdd		1.5	2.5	3.3	V
Input current	Idd	VDD=1.5V-3.3V	90	115	130	μΑ
Output impedance	Zout	94 dB SPL @ 1kHz, Single-ended output	-	-	200	Ohm
Power Supply Rejection	PSR	100mVpp Square wave @217Hz, A-weighted		-103		dBFS
Power Supply Rejection Ratio	PSRR	200mVpp sine wave at 1kHz, Vdd=1.8V		70		dB
DC output voltage	Vout_dc	VDD=1.5V-3.3V, Single ended output		0.85		V
Start-up time	tStart	Single-ended output		15		mS
Equivalent input noise	EIN	Noise measured with A- weighted filter		3		μV

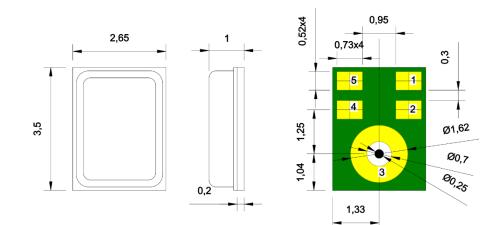
### TYPICAL FREQUENCY RESPONSE CURVE







# PACKAGE DIMENSION AND PIN LAYOUT



Item	Dimension	Tolerance(+/-)	Units
Length(L)	3.50	0.10	mm
Width(W)	2.65	0.10	mm
Height(H)	1.0	0.10	mm
Acoustic Port(AP)	Ø0.25	0.05	mm

Pin #	Pin Name	Туре	Description
1	Output	Signal	Output Signal
2	GND	Ground	Ground
3	GND	Ground	Ground
4	NA	NA	NA
5	VDD	Supply	Power supply



# **Product Specification**



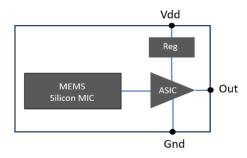
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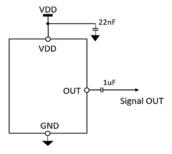
### **Terminology**

- 1. POWER: The Supply Voltage Positive Terminal (Pad name "VDD" in Electrical layout drawing) which is connected to the Microphone Sensing Element.
- 2. OUTPUT: The Output Terminal, where the electrical signal equivalent to the acoustic pressure is available, i.e. the Microphone output. (Pad name "OUTPUT" in Electrical layout drawing)
- 3. COMMON: The Terminal where the supply negative (Pad name "GND" in Electrical layout drawing) is connected to microphone package.
- 4. SENSITIVITY: Sensitivity is the open circuit output voltage amplitude for a given sound pressure at the microphone diaphragm. This is frequency dependent so typically quoted at 1KHz. Units are defined in dB logarithmic scale.
- 5. FREQUENCY RESPONSE: It is the plot of Sensitivity in dB vs frequency [Hz], it depends on transducer mechanism directional response, and reflection from room boundaries usually quote free-field response.
- 6. DIRECTIVITY: It is the response pattern that expresses the geometric shape of the region of sensitivity surrounding the microphone, omni directional, uni directional, bi- directional.

#### FUNCTIONAL BLOCK DIAGRAGM

#### ELECTRICAL BLOCK DIAGRAGM





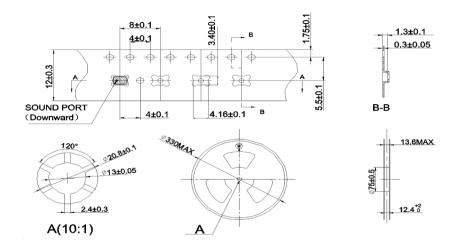


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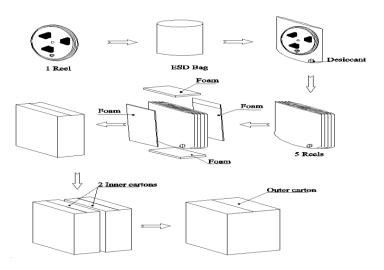
# **Analog Bottom Mount MEMS Microphone**

## **Packaging Information**

Tape & Reel Specification



### **Packaging Information**



Packaging quantity:
1 Reel=5000pcs
1 Innner Carton =5Reels=25000pcs
1 Outer Carton=2 Innner Cartons=50000pcs

Singapore +65 96235457

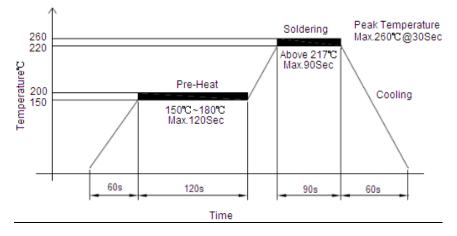




## **PROCESSING INFORMATION**

#### **Recommended Reflow Process Condition:**

Recommend reflow profile, solder reflow  $\leq 260^{\circ}$ C (for 30s Max of peak temperature).

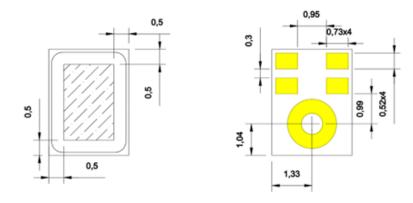


#### **Important Notes**

To minimize device damage:

- Do not wash or clean the boards after the reflow process.
- Do not apply airflow with pressure exceeding 0.3MPa to blow into the port hole within a distance of less than 5 cm.
- Do not expose the device to ultrasonic processing or cleaning.
- Do not apply a vacuum over the port hole of the microphone.

### Pickup Tool Pick Location & PCB Solder Pad Layout:



Recommended Pickup Location

Recommended Solder Pad Layout

United States +1 585 736 2223

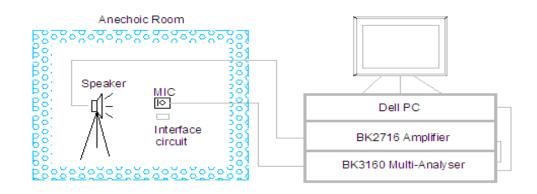


**Product Specification** 

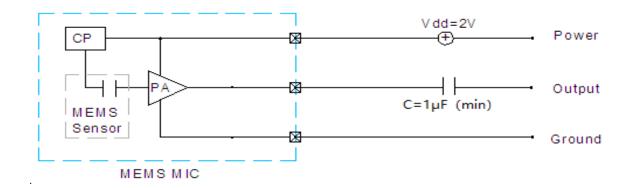


# **Analog Bottom Mount MEMS Microphone**

<u>TEST SETUP</u> <u>Sensitivity Test in Anechoic Room</u>



# Measurement Circuit







### RELIABILITY TEST

**Product Specification** 

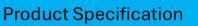
The samples should be placed in the room with 23+/-2°C, 55+/-10%R.H. for 2 hours at least before final measurement, unless otherwise specified.

Item	Detail	Standard
Simulated Reflow (Without Solder)	Samples for qualification testing require 3 Times 260±5 °C reflow solder profiles. 2 hours of settling time is required between each reflow profile test.	±3 dB
Static Humidity	Precondition at $+25$ °C for 1 hour. Then expose to $+85$ °C with 85% relative humidity for 1000 hours.	±3 dB
Temperature Shock	Each cycle shall consist of 30 minutes at -40°C, 30 minutes at +125°C with 5 minutes transition time. Test duration is for 30 cycles, starting from cold to hot temperature.	±3 dB
ESD Sensitivity	Perform ESD sensitivity threshold measurements for each contact according to MIL-STD-883G, Method 3015.7 for Human Body Model. Identify the ESD threshold levels indicating passage of 8000V Human Body Model.	±3 dB
Random Vibrations	Vibrate randomly along three perpendicular directions for 30 minutes in each direction, 4cycles from 20Hz~2000Hz with a peak acceleration 20g.	±3 dB
Mechanical Shock	Subject samples to half sine shock pulses (3000g±15% for 0.3ms) in each direction, totally 18 shocks.	±3 dB
Operation Life	Subject samples to +125°C for 168 hours under full maximum rated voltage.	±3 dB
Drop Test	The test was repeated in six directions for three times, Dropped from 1.5m height on to a steel surface, total 18 times and inspected for mechanical damage. Note: Sensitivity should vary within +/-3dB from initial sensitivity after test conditions are performed.	±3 dB

### **Delivery Standard:**

- Product delivered with 100% testing.
- All parts are tested for sensitivity at 1KHz.
- Product samples tested for frequency curve and SNR.







# PRODUCT NAMING CONVENTION

Company	Packaging size	Output	Mount	Sensitivity	Noise	Status
name IR Sensors &Systems	Length (mm) Width (mm)	A = Analog D = Digital	T=Top Mount B= Bottom mount	-dB (V/Pa)	dB	
IR	3526	А	В	38	70	Active

#### **DOCUMENT HISTORY**

Document Version	Date of Release	Changes
1.0	Feb. 15 <sup>th</sup> , 2024	Initial Version





## **INTERNATIONAL CONTACT INFORMATION**

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